NPN Epitaxial Silicon Transistor

KSC2383

ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	160	V
V _{CEO}	Collector-Emitter Voltage	160	V
V _{EBO}	Emitter-Base Voltage	6	V
۱ _C	Collector Current	1	А
Ι _Β	Base Current	0.5	А
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

(Values are at T_A = 25°C unless otherwise noted.) (Note 1)

Symbol	Parameter	Value	Unit
PD	Power Dissipation	900	mW
	Derate Above 25°C	7.2	mW/°C
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient	138	°C/W

1. PCB size: FR-4, 76 mm \times 114 mm \times 1.57 mm (3.0 inch \times 4.5 inch \times 0.062 inch) with minimum land pattern size.



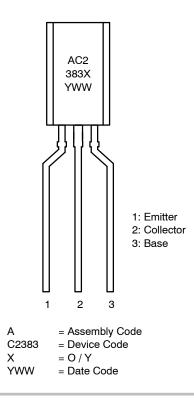
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TO-92 3 LF CASE 135AM

MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping
KSC2383OTA	TO–92 3 LF (Pb–Free)	2000 / Fan-Fold
KSC2383YTA	TO–92 3 LF (Pb–Free)	2000 / Fan-Fold

ELECTRICAL CHARACTERISTICS

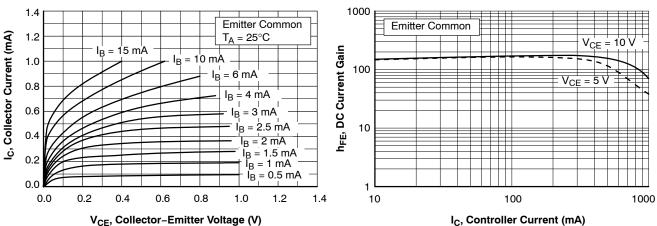
(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-Off Current	V _{CB} = 150 V, I _E = 0	-	-	1	μΑ
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 6 V, I_{C} = 0$	-	-	1	μΑ
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 10 mA, I _B = 0	160	-	-	V
h _{FE}	DC Current Gain	$V_{CE} = 5 \text{ V}, I_{C} = 200 \text{ mA}$	60	-	320	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 500 mA, I _B = 50 mA	-	-	1.5	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$	0.45	-	0.75	V
f _T	Current Gain Bandwidth Product	V _{CE} = 5 V, I _C = 200 mA	20	100	-	MHz
C _{ob}	Output Capacitance	V_{CB} = 10 V, I _E = 0, f = 1 MHz	-	-	20	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

h_{FE} CLASSIFICATION

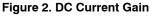
Classification	R	0	Y
h _{FE}	60 ~ 120	100 ~ 200	160 ~ 320

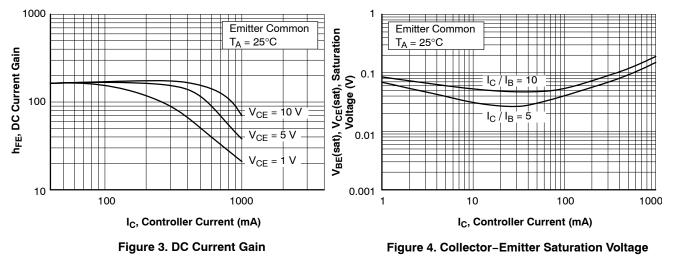


TYPICAL PERFORMANCE CHARACTERISTICS

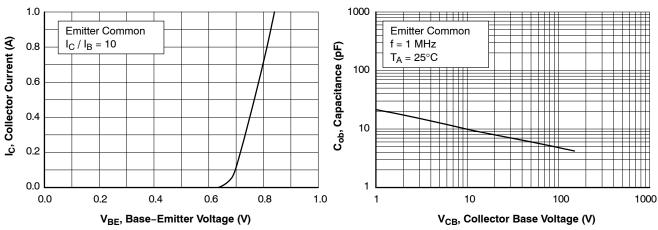








KSC2383



TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



Figure 6. Collector Output Capacitance

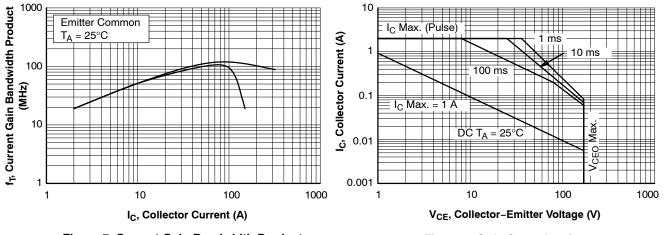
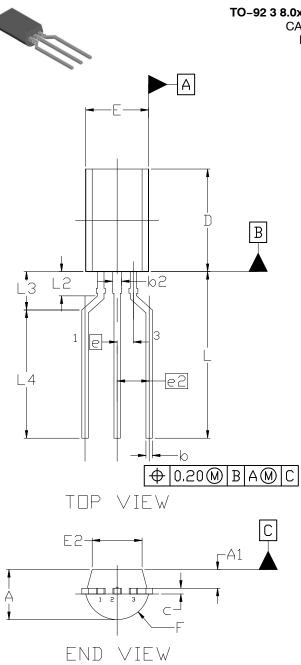


Figure 7. Current Gain Bandwidth Product

Figure 8. Safe Operating Area

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





TO-92 3 8.0x4.9 (LEADFORMED) CASE 135AM

ISSUE B

DATE 14 JAN 2021

NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, GATE REMAINS AND TIE BAR PROTRUSIONS.
- 4. DIMENSION & AND &2 DOES NOT INCLUDE DAMBAR PROTRUSION. DIMENSION &2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
А	3.70	3.90	4.10	
A1	1.25	1.45	1.65	
b	0.35	0.50	0.60	
b2	0.62		0.78	
С	0.35	0.45	0.55	
D	7.80	8.00	8.20	
Е	4.70	4.90	5.10	
E2	3.70	3.90	4.10	
е	1.27 BSC			
e2	2.50 BSC			
F	2.45 REF			
L	13.00 REF			
L2	1.50		1.90	
L3	2.60		3.40	
L4	10.40 REF			

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